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## ■ Special Issue on Si-Based Materials and Devices

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### Preface

Chuanbo Li, Jinsong Xia, and Linwei Yu

061001 **Emerging technologies in Si active photonics**

[29 pages] Xiaoxin Wang and Jifeng Liu

061002 **Carrier transport mechanisms in semiconductor nanostructures and devices**

[13 pages] M. A. Rafiq

061003 **Dopant atoms as quantum components in silicon nanoscale devices**

[8 pages] Xiaosong Zhao, Weihua Han, Hao Wang, Lihong Ma, Xiaoming Li, Wang Zhang, Wei Yan, and Fuhua Yang

061004 **Controllable growth of GeSi nanostructures by molecular beam epitaxy**

[15 pages] Yingjie Ma, Tong Zhou, Zhenyang Zhong, and Zuimin Jiang

061005 **Research progress of Ge on insulator grown by rapid melting growth**

[10 pages] Zhi Liu, Juanjuan Wen, Chuanbo Li, Chunlai Xue, and Buwen Cheng

061006 **Recent progress in GeSn growth and GeSn-based photonic devices**

[6 pages] Jun Zheng, Zhi Liu, Chunlai Xue, Chuanbo Li, Yuhua Zuo, Buwen Cheng, and Qiming Wang

061007 **Si nanocrystals-based multilayers for luminescent and photovoltaic device applications**

[10 pages] Peng Lu, Dongke Li, Yunqing Cao, Jun Xu, and Kunji Chen

061008 **Light-emitting diodes based on colloidal silicon quantum dots**

[12 pages] Shuangyi Zhao, Xiangkai Liu, Xiaodong Pi, and Deren Yang

061009 **Silicon-graphene photonic devices**

[8 pages] Yanlong Yin, Jiang Li, Yang Xu, Hon Ki Tsang, and Daoxin Dai

063001 **Ammonia sensing using arrays of silicon nanowires and graphene**

[7 pages] K. Fobelets, C. Panteli, O. Sydoruk, and Chuanbo Li